



S E M I C O N D U C T O R

SR1020D1 THRU SR10200D1

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts

Forward Current - 10.0Amperes

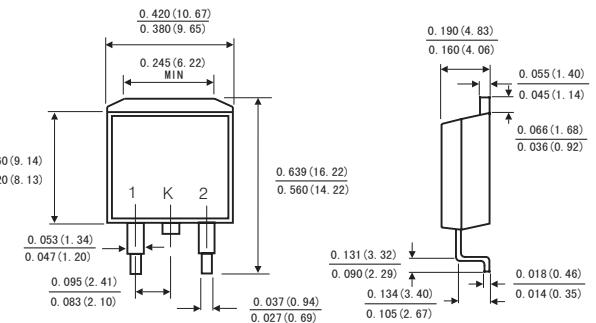
FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- Single rectifier construction
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case
- Component in accordance to RoHS 2011/65/EU



TO-263

D2PAK



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC TO-263 molded plastic body
- Terminals: Solderable per MIL-STD-202, method 208
- Polarity: As marked
- Mounting Position: Any
- Weight: 0.08ounce, 2.24 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified, Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	SR 1020D1	SR 1030D1	SR 1045D1	SR 1060D1	SR 10100D1	SR 10150D1	SR 10200D1	Units			
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	45	60	100	150	200	Volts			
Maximum RMS voltage	V _{RMS}	14	21	32	42	70	105	140	Volts			
Maximum DC blocking voltage	V _{DC}	20	30	45	60	100	150	200	Volts			
Maximum average forward rectified current (see Fig.1)	I _(AV)	5.0 10.0							Amps			
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	150.0							Amps			
Maximum instantaneous forward voltage at 5.0 A per leg (Notes 1)	V _F	0.60		0.75	0.85	0.90	0.95		Volts			
Maximum instantaneous reverse current at rated DC blocking voltage (Notes 1)	T _s =25°C	200			50				μA			
	T _s =100°C	5			-				mA			
	T _s =125°C	-			5							
Typical thermal resistance (Notes 2)	R _{θJC}	2.5							°C/W			
Operating junction temperature range	T _J	-65 to +150							°C			
Storage temperature range	T _{STG}	-65 to +150							°C			

Notes: 1. Pulse test: 300 μ s pulse width, 1% duty cycle

2. Thermal resistance from junction to case

RATINGS AND CHARACTERISTIC CURVES SR1020D1 THRU SR10200D1

FIG.1-FORWARD CURRENT DERATING CURVE

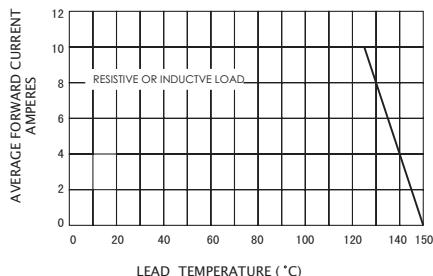


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

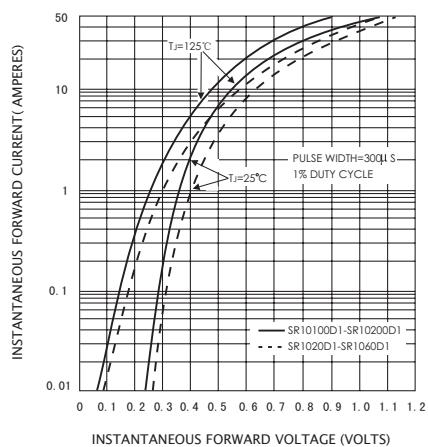


FIG.5-TYPICAL JUNCTION CAPACITANCE

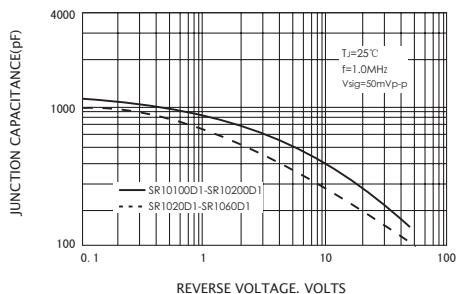


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

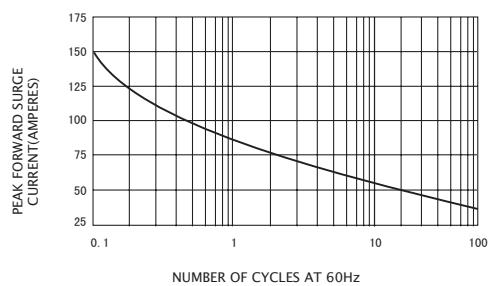


FIG.4-TYPICAL REVERSE CHARACTERISTICS

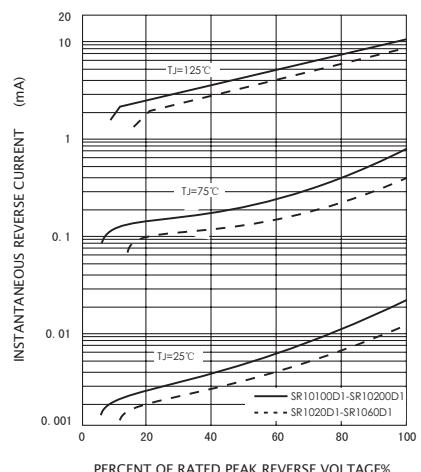


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

